

#### 4-Channel Active Base for the Onsemi ArrayJ-30035-64P-PCB

#### **Features**

Supports the Onsemi ArrayJ-30035-64P-PCB 8x8 array of 3mm SiPMs

"HF" Variant: Horizontal signal connector on the front, array located on the front

Four encoded position signals for event centroid calculations: X+, X-, Y+, Y-

DC-coupled signal path

Low power consumption

Patented diode-coupled charge division readout, superior to traditional resistive readout

Improved spatial uniformity

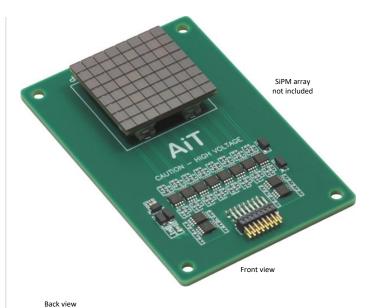
Faster rise time

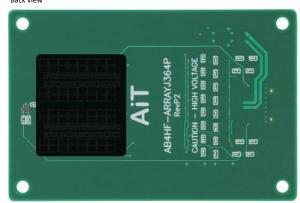
Reduced image noise

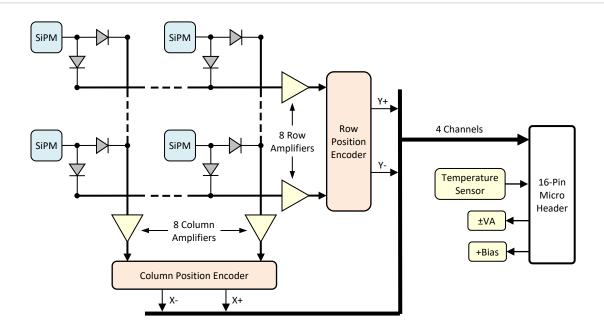
Precision temperature sensor

Four mounting holes for #4 or M3 hardware

Fast output signals are not connected







### AB4HF-ARRAYJ364P

# **Specifications**

#### **Position Signal Output**

Encoding Charge division multiplexed to

4 output channels: X+, X-, Y+, Y-

 $\mbox{ Gain } \mbox{ 750} \mbox{ transimpedance gain } \mbox{}$ 

Output voltage  $0 \rightarrow -1V$  into  $100\Omega$  load

Output impedance 100Ω

Output current 50mA maximum

**Temperature Sensor** 

Output voltage 500mV + 10mV per °C

Output current 10mAOutput impedance  $100\Omega$ Accuracy  $\pm 0.5^{\circ}C$ 

Bias Voltage +29V typical (refer to SiPM data)

Voltage clamp 47V Zener diode

500mW maximum

Amplifier Voltage ( $\pm$ VA)  $\pm 2.8V \rightarrow \pm 5.5V$  DC maximum

Current ±40mA typical

(Iq, no signal, no load)

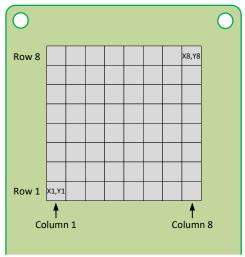
Signal Connector Horizontal 16-pin 2-row header

0.050" pin pitch

Mating assembly Samtec FFSD-08-D-XX.XX-01-N

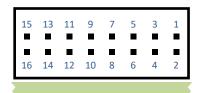
(XX.XX = length in inches)

## **Channel Map**



Front view

## **Signal Connector**



**PCB Side View** 

Pin	Function	Pin	Function	
1	Temperature	2	Ground	
3	X-	4	Ground	
5	X+	6	Ground	
7	-VA	8	Ground	
9	+VA	10	Ground	
11	Υ-	12	Ground	
13	Y+	14	Ground	
15	+Bias	16	Ground	

## **AB4HF-ARRAYJ364P**

#### **4-Channel Position Encoder**

#### **Row & Column Encoder Weights**

Row# or Col# (for X- or Y-)	Row# or Col# (for X+ or Y+)	Fraction (ideal)	Fraction (actual)	% Error	Notes
1	8	0.1250	0.1250	0.00 %	
2	7	0.2500	0.2483	-0.68 %	
3	6	0.3750	0.3731	-0.51 %	Sum of X- and X+ fractions
4	5	0.5000	0.5000	0.00 %	or Y- and Y+ fractions
5	4	0.6250	0.6250	0.00 %	= 1.1250
6	3	0.7500	0.7500	0.00 %	Independent of signal position
7	2	0.8750	0.8876	1.44 %	
8	1	1.0000	1.0000	0.00 %	

**Note:** Errors exclude component tolerances

#### **Output Signals**

X- = (SiPM signal) \* (encoder gain) \* (X- fraction)

X+ = (SiPM signal) \* (encoder gain) \* (X+ fraction)

Y- = (SiPM signal) \* (encoder gain) \* (Y- fraction)

Y+ = (SiPM signal) \* (encoder gain) \* (Y+ fraction)

Typical event position calculation:

X column = (X + - X -) / (X + + X -)

Y row = (Y + - Y -) / (Y + Y -)

#### **Example**

SiPM signal at column 4, row 3 (excluding encoder gain)

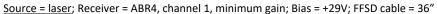
X- = (Column 4 signal) \* 0.5000

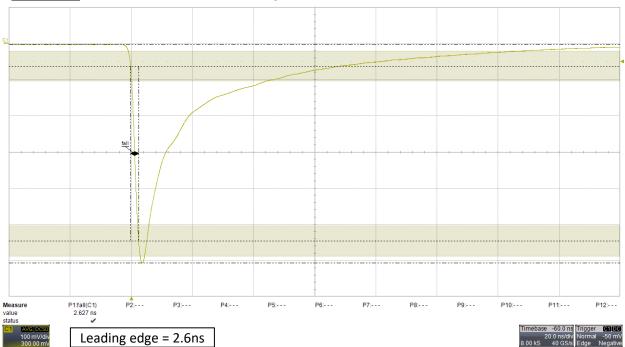
**X+** = (Column 4 signal) \* 0.6250

**Y-** = (Row 3 signal) \* 0.3731

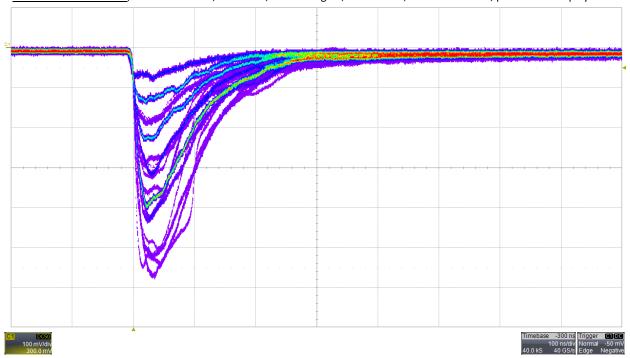
**Y+** = (Row 3 signal) \* 0.7500

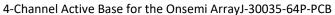
# **Typical Signals**









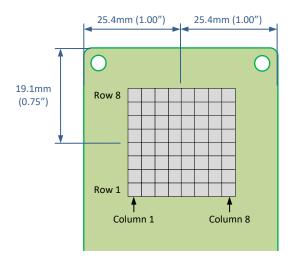




### Mechanical

# **Back View Front View** 50.8mm (2.00") Ø 3.18mm AB4HF-ARRAYJ364P (0.125")qty = 4 SiPM pin 1 Epoxy coated area 76.2mm (3.00")AB4HF-ARRAYJ364P RevP2 CAUTION - HIGH VOLTAGE ----3.81mm (0.15")Temperature sensor Align pin 1 with the 3.81mm red conductor on the Measurement tolerance: ±0.020" (0.15")Samtec FFSD cable

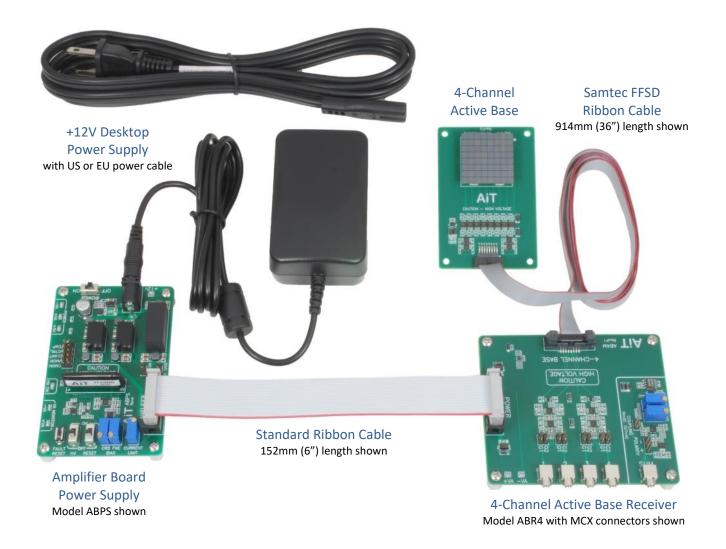
#### **Array Location**





4-Channel Active Base for the Onsemi ArrayJ-30035-64P-PCB

#### **4-Channel Active Base Readout Kit**



#### Components

Each component is available separately. Refer to each datasheet for details.

The Active Base includes a 914mm (36") Samtec FFSD micro-pitch ribbon cable.

The Amplifier Board Power Supply includes a 12V desktop power supply and a HV80 bias voltage power supply.

The 4-channel Active Base Receiver includes a 152mm (6") power supply ribbon cable and a breakout board to connect any external power supply.

#### AB4HF-ARRAYJ364P

4-Channel Active Base for the Onsemi ArrayJ-30035-64P-PCB

# **Safety Information**



# WARNING – High Voltage

- High voltage may be present during operation
- High voltage stored on capacitors may be present after power is removed
- Improper handling may result in personnel injury or equipment damage

This high-voltage device must be used only by personnel trained and qualified in safe handling, installation, and operation of high-voltage equipment.



# **CAUTION** – Electrostatic Discharge (ESD) Sensitivity

The circuit board can be damaged by electrostatic discharge. Observe precautions for handling electrostatic sensitive devices. Handle only at static-safe workstations.

## **High-Gain Photodetectors**

High-gain photodetectors such as silicon photomultipliers may conduct damaging currents if exposed to high optical signal levels while the bias voltage is applied, or if the bias voltage exceeds the recommended operating range. These devices must be operated only in low-light conditions, and only within the manufacturer's recommended bias voltage range.

## **Handling and Disassembly**

This product may be provided with a protective enclosure. Disassembled enclosure components and circuit boards may contain sharp edges. Take appropriate safety precautions while assembling or disassembling the enclosure and handling disassembled components.

#### **Indoor Use Only**

Do not operate this product in a wet or damp environment. Do not operate in an explosive atmosphere.

Use of this product, and AiT Instruments' liability related to use of this product, is further governed by AiT Instruments' standard terms and conditions of sale, which were provided upon purchase of this product.